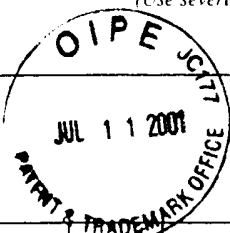


Form PTO-1449 INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary)	Docket Number 204552016500	Application Number 09/412,328
	Applicant Yuichi SATO	
	Filing Date October 5, 1999	Group Art Unit 2811
	Mailing Date July 11, 2001	



U.S. PATENT DOCUMENTS

Examiner Initials	Ref. No.	Date	Document No.	Name	Class	Subclass	Filing Date If Appropriate
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FOREIGN PATENT DOCUMENTS

Examiner Initials	Ref. No.	Date	Document No.	Country	Class	Subclass	Translation YES NO
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OTHER DOCUMENTS

(including author, title, Date, Pertinent Pages, Etc.)

Examiner Initials	Ref. No.	Title
	1.	Assaderaghi et al., 1994 "A dynamic threshold voltage mosfet (DTMOS) for very low voltage operation" IEEE Electron Device Letters Vol. 15, pp 510-512.
	2.	Andoh et al., 1994 "Design methodology for low-voltage mosfets" IEEE International Electron Devices Meeting, Technical Digest, pp 79-82.
	3.	Assaderaghi et al., 1994 "A dynamic threshold voltage mosfet (DTMOS) for ultra-low voltage operation" IEEE International Electron Devices Meeting, Technical Digest, pp 809-812.

not provided - not considered

EXAMINER: (examiner)

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